12-BIT 1	捷多邦,专业PCB打样工厂,24小时加 <b>会补了4</b> CBT16214C -OF-3 FET MULTIPLEXER/DEMULTIPLEXER CH WITH -2-V UNDERSHOOT PROTECTION SCDS121B - JUNE 2003 - REVISED OCTOBER 2003
<ul> <li>Member of the Texas Instruments</li></ul>	DGG OR DL PACKAGE
Widebus™ Family	(TOP VIEW)
<ul> <li>Undershoot Protection for Off-Isolation on</li></ul>	S0 [ 1 56 ] S1
A and B Ports Up To –2 V	1A [ 2 55 ] S2
<ul> <li>Bidirectional Data Flow, With Near-Zero</li></ul>	1B3 [] 3 54 ]] 1B1
Propagation Delay	2A [] 4 53 [] 1B2
<ul> <li>Low ON-State Resistance (r<sub>on</sub>)</li></ul>	2B3 5 52 2B1
Characteristics (r <sub>on</sub> = 3 Ω Typical)	3A 6 51 2B2
<ul> <li>Low Input/Output Capacitance Minimizes</li></ul>	3B3 [] 7 50 ]] 3B1
Loading and Signal Distortion	GND [] 8 49 ]] GND
(C <sub>io(OFF)</sub> = 5.5 pF Typical)	4A [] 9 48 [] 3B2
<ul> <li>Data and Control Inputs Provide</li></ul>	4B3 [] 10 47 ]] 4B1
Undershoot Clamp Diodes	5A [] 11 46 ]] 4B2
<ul> <li>Low Power Consumption         <ul> <li>(I<sub>CC</sub> = 3 μA Max)</li> </ul> </li> <li>V<sub>CC</sub> Operating Range From 4 V to 5.5 V</li> </ul>	5B3 [] 12 45 ] 5B1 6A [] 13 44 ] 5B2 6B3 [] 14 43 ] 6B1
<ul> <li>Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)</li> </ul>	7A         15         42         6B2           7B3         16         41         7B1           V <sub>CC</sub> 17         40         7B2
<ul> <li>Control Inputs Can Be Driven by TTL or</li></ul>	8A [] 18 39 ]] 8B1
5-V/3.3-V CMOS Outputs	GND [] 19 38 ]] GND
<ul> <li>I<sub>off</sub> Supports Partial-Power-Down Mode</li></ul>	8B3 [] 20 37 ]] 8B2
Operation	9A [] 21 36 ]] 9B1
Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II	9B3 [] 22 35 [] 9B2 10A [] 23 34 [] 10B1 10B3 [] 24 33 [] 10B2
<ul> <li>ESD Performance Tested Per JESD 22         <ul> <li>2000-V Human-Body Model (A114-B, Class II)</li> <li>1000-V Charged-Device Model (C101)</li> </ul> </li> </ul>	10B3 [] 24 33 [] 10B2 11A [] 25 32 ]] 11B1 11B3 [] 26 31 ]] 11B2 12A [] 27 30 ]] 12B1
<ul> <li>Supports Both Digital and Analog</li> </ul>	12B3 [28 29] 12B2

## description/ordering information

Low-Distortion Signal Gating

Applications: PCI Interface, Bus Isolation,

TA	PACKA	AGE <sup>†</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING				
	SSOP - DL	Tube	SN74CBT16214CDL	007400440				
4000 40 0500		Tape and reel	SN74CBT16214CDLR	CBT16214C				
–40°C to 85°C	TSSOP - DGG	Tube	SN74CBT16214CDGG	CBT16214C				
		Tape and reel	SN74CBT16214CDGGR	CB110214C				

## ORDERING INFORMATION

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION SCDS121B - JUNE 2003 - REVISED OCTOBER 2003

## description/ordering information (continued)

The SN74CBT16214C is a high-speed TTL-compatible FET multiplexer/demultiplexer with low ON-state resistance ( $r_{on}$ ), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT16214C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT16214C is a 12-bit 1-of-3 multiplexer/demultiplexer. The select (S0, S1, S2) inputs control the data path of each multiplexer/demultiplexer. When the multiplexer/demultiplexer is enabled, the A port is connected to the B port, allowing bidirectional data flow between ports. When the multiplexer/demultiplexer is disabled, a high-impedance state exists between the A and B ports.

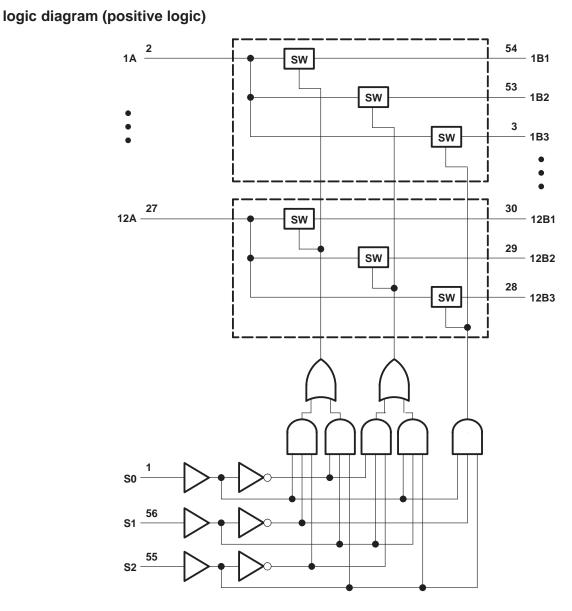
This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, each select input should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

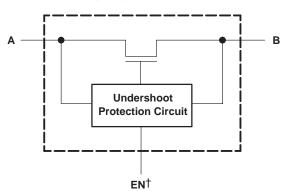
	INPUTS		INPUT/OUTPUT	FUNCTION
S2	S1	S0	A	TONOTION
L	L	L	Z	Disconnect
L	L	Н	B1	A port = B1 port
L	Н	L	B2	A port = B2 port
L	Н	Н	Z	Disconnect
н	L	L	Z	Disconnect
н	L	Н	B3	A port = B3 port
н	Н	L	B1	A port = B1 port
н	Н	Н	B2	A port = B2 port

#### FUNCTION TABLE

## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION SCDS121B - JUNE 2003 - REVISED OCTOBER 2003



simplified schematic, each FET switch (SW)



<sup>†</sup> EN is the internal enable signal applied to the switch.



## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION SCDS121B - JUNE 2003 - REVISED OCTOBER 2003

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

$ \begin{array}{llllllllllllllllllllllllllllllllllll$	7 V 7 V mA mA mA mA C/W
Package thermal impedance, θ <sub>JA</sub> (see Note 5): DGG package	
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to ground unless otherwise specified.

- 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 3. VI and VO are used to denote specific conditions for VI/O.
- 4. I and IO are used to denote specific conditions for I/O.
- 5. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
VCC	Supply voltage	4	5.5	V
VIH	High-level control input voltage	2	5.5	V
$V_{IL}$	Low-level control input voltage	0	0.8	V
V <sub>I/O</sub>	Data input/output voltage	0	5.5	V
Т <sub>А</sub>	Operating free-air temperature	-40	85	°C

NOTE 6: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

SCDS121B - JUNE 2003 - REVISED OCTOBER 2003

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER		TEST CONDITIONS			′P†	MAX	UNIT
VIK	Control inputs	V <sub>CC</sub> = 4.5 V,	I <sub>IN</sub> = -18 mA				-1.8	V
VIKU	Data inputs	V <sub>CC</sub> = 5 V,	0 mA > I <sub>I</sub> $\ge$ -50 mA, V <sub>IN</sub> = V <sub>CC</sub> or GND,	Switch OFF			-2	V
IIN	Control inputs	V <sub>CC</sub> = 5.5 V,	$V_{IN} = V_{CC} \text{ or } GND$				±1	μA
IOZ <sup>‡</sup>		V <sub>CC</sub> = 5.5 V,	$V_{O} = 0$ to 5.5 V, $V_{I} = 0$ ,	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			±10	μΑ
loff		$V_{CC} = 0,$	$V_{O} = 0$ to 5.5 V,	$V_{I} = 0$			10	μΑ
ICC		V <sub>CC</sub> = 5.5 V,	$I_{I/O} = 0,$ $V_{IN} = V_{CC} \text{ or GND},$	Switch ON or OFF			3	μΑ
∆ICC§	Control inputs	V <sub>CC</sub> = 5.5 V,	One input at 3.4 V,	Other inputs at $V_{CC}$ or GND			2.5	mA
C <sub>in</sub>	Control inputs	$V_{IN} = 3 V \text{ or } 0$				3.5		pF
C: (0.77)	A port	Vice 2Vice 0	Switch OFF			10		pF
C <sub>io(OFF)</sub>	B port	$V_{I/O} = 3 V \text{ or } 0,$	Switch OFF,	$V_{IN} = V_{CC}$ or GND		5.5		pF
C <sub>io(ON)</sub>	-	V <sub>I/O</sub> = 3 V or 0,	Switch ON,	$V_{IN} = V_{CC}$ or GND		18		pF
		$V_{CC} = 4 V,$ TYP at $V_{CC} = 4 V$	V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA		8	12	
r <sub>on</sub> ¶			1	I <sub>O</sub> = 64 mA		3	6	Ω
		V <sub>CC</sub> = 4.5 V	$V_{I} = 0$	I <sub>O</sub> = 30 mA		3	6	
			V <sub>I</sub> = 2.4 V,	IO = -15 mA		5	10	

VIN and IIN refer to control inputs. VI, VO, II, and IO refer to data pins.

<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V (unless otherwise noted),  $T_A$  = 25°C.

<sup>‡</sup> For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

<sup>§</sup> This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

¶ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

# switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	TO	V <sub>CC</sub> = 4 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
<sup>t</sup> pd <sup>#</sup>	A or B	B or A		0.24		0.15	ns
<sup>t</sup> pd(s)	S	А		6.7	1.5	6.3	ns
ten	S	В		7.2	1.5	6.6	ns
t <sub>dis</sub>	S	В		7.5	1.5	7.3	ns

<sup>#</sup> The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

SCDS121B - JUNE 2003 - REVISED OCTOBER 2003

## undershoot characteristics (see Figures 1 and 2)

PARAMETER	TEST CONDITIONS				TYP <sup>†</sup>	MAX	UNIT
νουτυ	$V_{CC} = 5.5 V_{,}$	Switch OFF,	$V_{IN} = V_{CC}$ or GND	2	V <sub>OH</sub> -0.3		V

<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V (unless otherwise noted),  $T_A$  = 25°C.

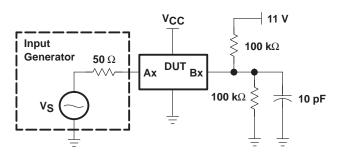
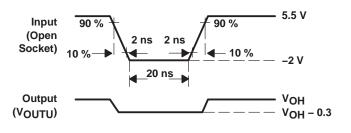


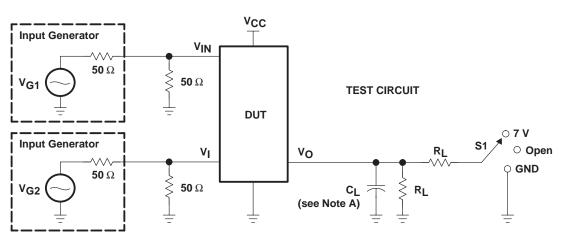
Figure 1. Device Test Setup





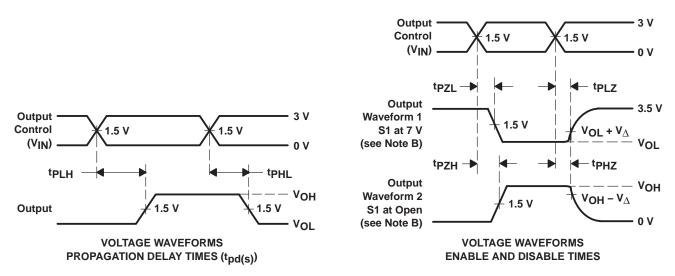
## SN74CBT16214C 12-BIT 1-OF-3 FET MULTIPLEXER/DEMULTIPLEXER 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

SCDS121B - JUNE 2003 - REVISED OCTOBER 2003



### PARAMETER MEASUREMENT INFORMATION

TEST	VCC	S1	RL	٧I	сL	$v_\Delta$
<sup>t</sup> pd(s)	5 V ± 0.5 V 4 V	Open Open	<b>500</b> Ω <b>500</b> Ω	V <sub>CC</sub> or GND V <sub>CC</sub> or GND	50 pF 50 pF	
<sup>t</sup> PLZ <sup>/t</sup> PZL	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	7 V 7 V	<b>500</b> Ω <b>500</b> Ω	GND GND	50 pF 50 pF	0.3 V 0.3 V
<sup>t</sup> PHZ <sup>/t</sup> PZH	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	Open Open	<b>500</b> Ω <b>500</b> Ω	V <sub>CC</sub> V <sub>CC</sub>	50 pF 50 pF	0.3 V 0.3 V



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns. t<sub>f</sub>  $\leq$  2.5 ns. D. The outputs are measured one at a time with one transition per measurement.
  - D. The outputs are measured one at a time v
  - E. tpLZ and tpHZ are the same as t<sub>dis</sub>.
    F. tpZI and tpZH are the same as t<sub>en</sub>.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
     H. All parameters and waveforms are not applicable to all devices.

## Figure 3. Test Circuit and Voltage Waveforms





## PACKAGE OPTION ADDENDUM

24-Feb-2006

## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74CBT16214CDGGRE4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT16214CDGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT16214CDL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT16214CDLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT16214CDLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT16214CDLRG4	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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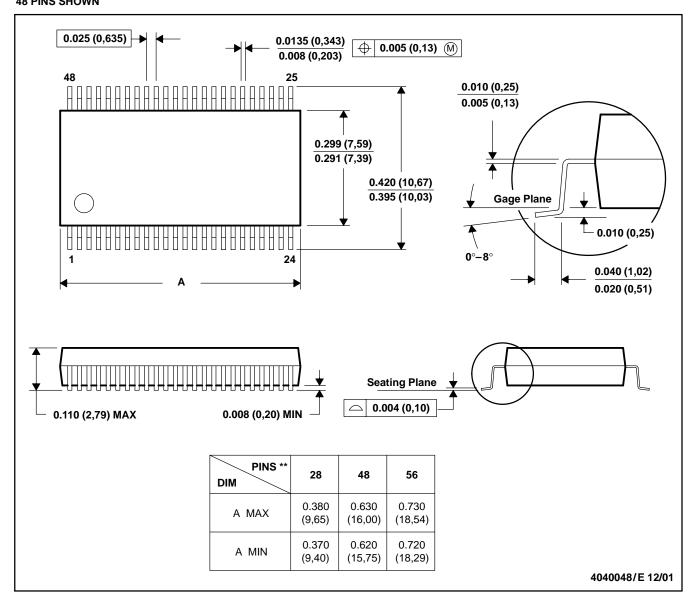
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## **MECHANICAL DATA**

MSSO001C - JANUARY 1995 - REVISED DECEMBER 2001

#### PLASTIC SMALL-OUTLINE PACKAGE

## DL (R-PDSO-G\*\*) 48 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

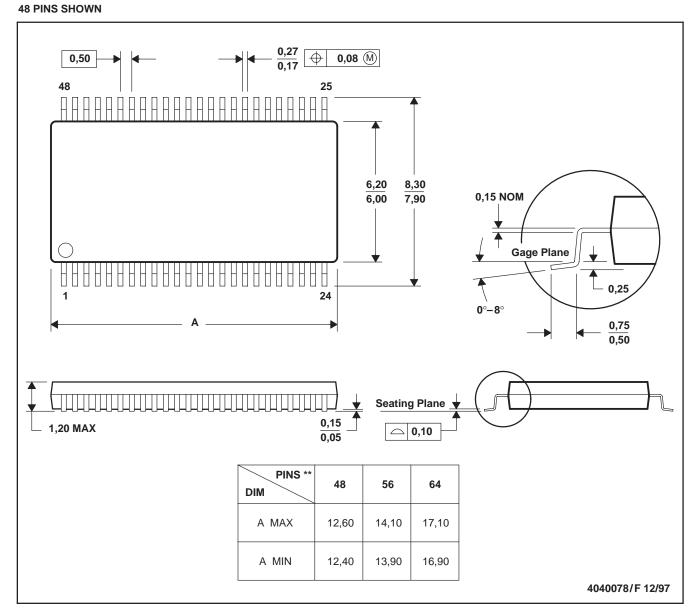


## **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

## PLASTIC SMALL-OUTLINE PACKAGE

DGG (R-PDSO-G\*\*)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153



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